

## Silicon Epitaxial Planar Diode

### FEATURES

- Small Surface Mounting
- High Speed  $t_f=1.2\text{ns}$  Typ.
- High Reliability With High Surge Current Handling Capability
- High speed switching
- Qualified to AEC-Q101 Standards for High Reliability

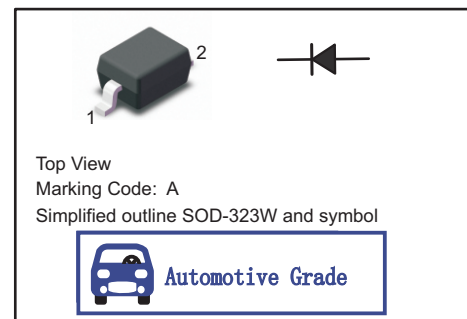
### MECHANICAL DATA

- Case: SOD-323W
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 5.48mg / 0.00019oz

Maximum Ratings at 25 °C

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Parameter	Symbols	AT-1SS355WB	Units
Non-Repetitive Peak reverse voltage	$V_{RM}$	90	V
DC Reverse Voltage	$V_R$	80	V
Peak forward Current	$I_{FM}$	225	mA
Average Rectified Output Current	$I_O$	100	mA
Peak forward surge current (1ms)	$I_{FSM}$	1	A
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ +150	°C

### ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbols	AT-1SS355WB	Units
Forward voltage $I_F=100\text{mA}$	$V_F$	1.2	V
Reverse current $V_R=80\text{V}$	$I_R$	0.1	$\mu\text{A}$
Capacitance between terminals $V_R=0.5\text{V}$ $f=1\text{MHz}$	$C_T$	3	pF
Reverse Recovery Time $I_F=10\text{mA}, V_R=6\text{V}, R_L=100\Omega$	trr	4	ns



Fig.1 FORWARD CHARACTERISTICS

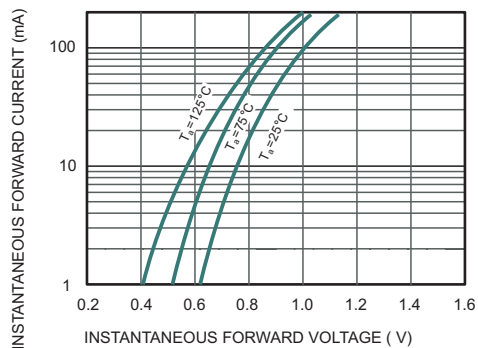


Fig.2 Typical Reverse Characteristics

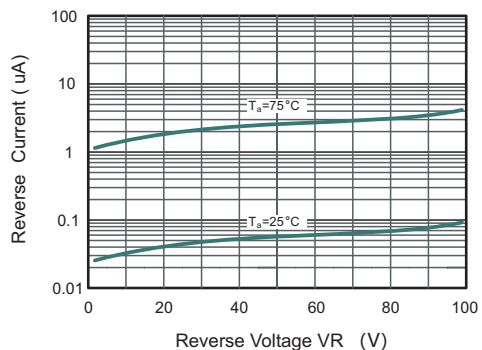
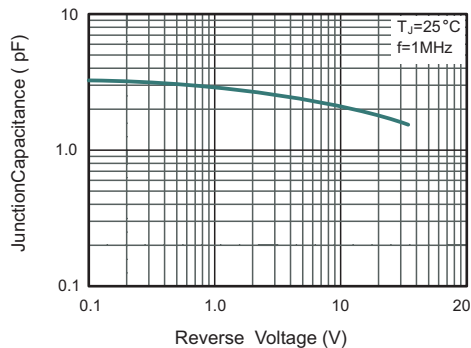


Fig.3 Typical Junction Capacitance

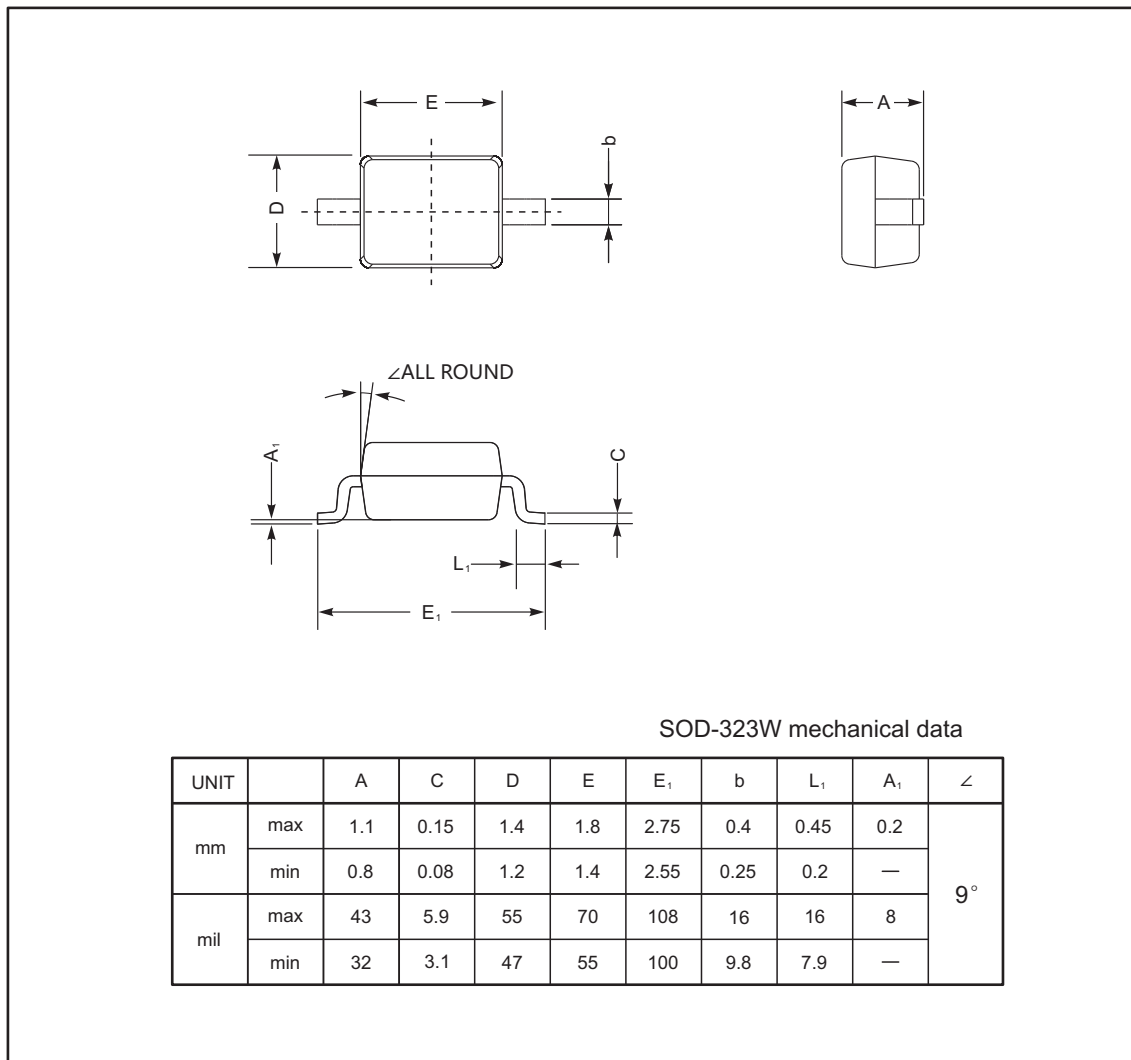




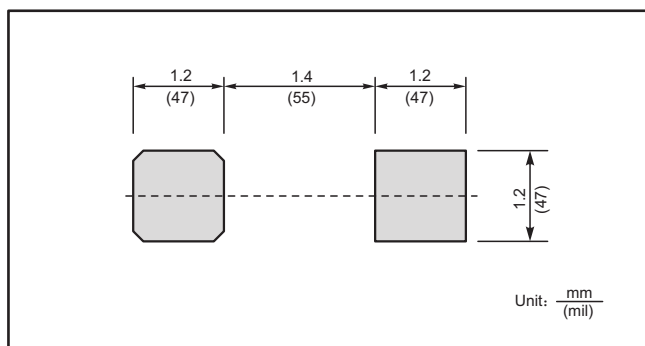
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323W



The recommended mounting pad size



Marking

Type number	Marking code
AT-1SS355WB	A